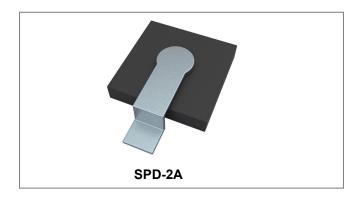






# 65SPB015/A Power Surface Mount Schottky Rectifier



#### **Features**

- 100 °C T<sub>J</sub> operation
- Low forward voltage drop
- High surge capacities
- High frequency operation
- Guaranteed reverse avalanche capability
- Low profile surface mount package
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

# Schematic & Pin Configuration



### **Applications**

- Switching power supply
- Redundant power subsystems
- Reverse battery protection
- Converters
- Many other high current AC/DC power supplies

### **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	15	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>C</sub> =116°C, rectangular wave form	60	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	860	Α







### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V <sub>F1</sub>	@ 60A, Pulse, T <sub>J</sub> = 25 °C	-	0.41	V
	V <sub>F2</sub>	@ 60A, Pulse, T <sub>J</sub> = 75 °C	-	0.37	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_R, \text{ Pulse}, \\ T_J = 25  ^{\circ}\text{C}$	5	20	mA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R, \text{ Pulse}, \\ T_J = 100  ^{\circ}\text{C}$	500	1000	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C f_{SiG} = 1MHz$	3300	3600	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +125	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +100	°C
Typical Thermal Resistance Junction to Case	R <sub>θJC</sub>	DC operation	0.37	°C/W
Approximate Weight	wt	-	1.1	g

## **Mechanical Dimensions (Inches/Millimeters)** 0.090±0.010 0.105±0.010 0.015 (2.54±0.25) (0.38) (2.67±0.25) 0.040 0.150(3.81)Dia 0.150(3.81)Dia (2.92) 0.400±0.010-(10.16±0.025) 0.400±0.010-(10.16±0.025) SPD-2 SPD-2A

## **Suffix "R" Denotes Reversed Polarity**

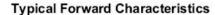
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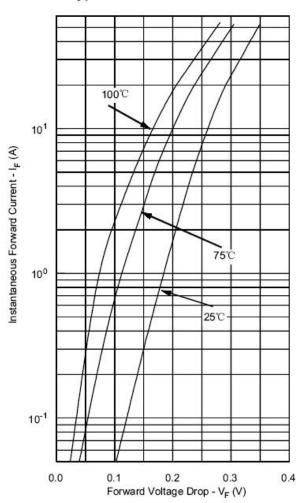




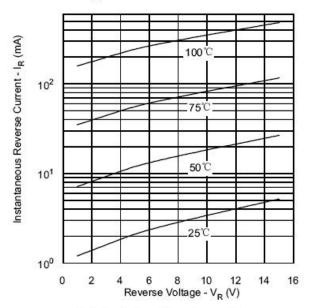


### **Ratings and Characteristics Curves**

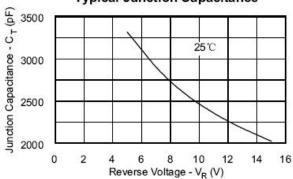




#### Typical Reverse Characteristics



#### **Typical Junction Capacitance**



### **Ordering Information**

Device	Package	Shipping	
65SPB015(A)	SPD-2A(Pb-Free)	100pcs/ box	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

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